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FAST RECOVERY DIODE

ARF912

Repetitive voltage up to **2600 V**
Mean forward current **754 A**
Surge current **6 kA**

FINAL SPECIFICATION
June 17 - Issue: 5

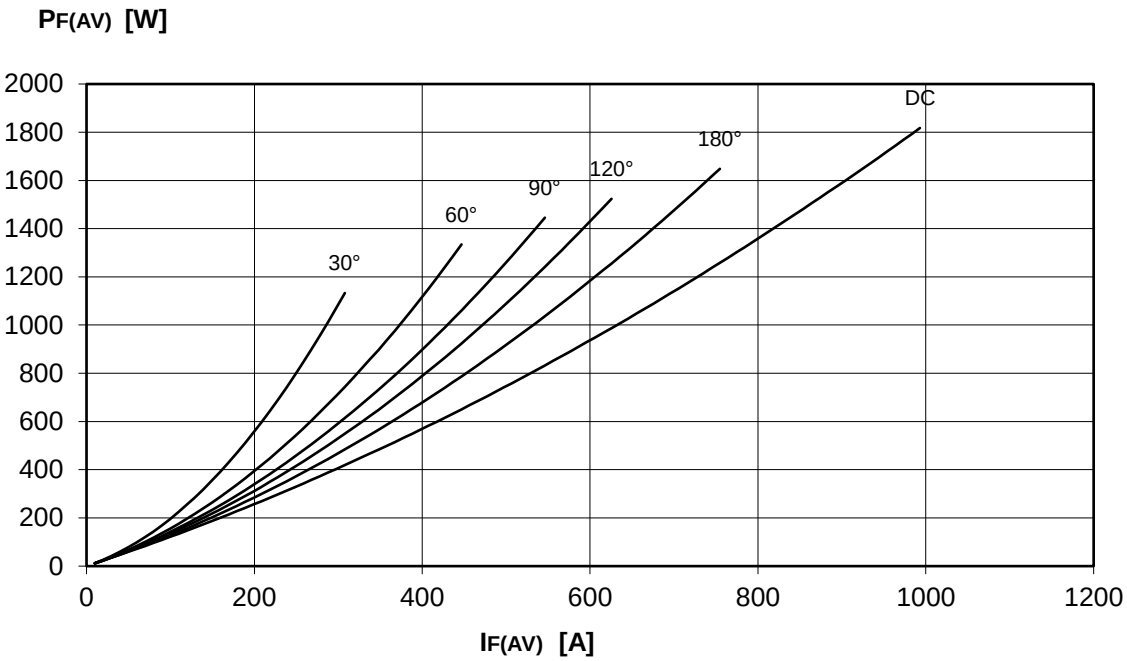
Symbol	Characteristic	Conditions	Tj [°C]	Value	Unit
BLOCKING					
V_{RRM}	Repetitive peak reverse voltage		150	2600	V
V_{RSM}	Non-repetitive peak reverse voltage		150	2700	V
I_{RRM}	Repetitive peak reverse current	V=VRRM	150	50	mA
CONDUCTING					
$I_{F(AV)}$	Mean forward current	180° sin, 50 Hz, Th=55°C, double side cooled		754	A
$I_{F(AV)}$	Mean forward current	180°square, 50 Hz, Th=55°C, double side cooled		755	A
I_{FSM}	Surge forward current	Sine wave, 10 ms riappled reverse voltage up to 50% VRSM	150	6,4	kA
I^2t	I^2t			205 x 10^3	A^2s
V_{FM}	Forward voltage	Forward current = 1200 A	25	2,30	V
$V_{F(TO)}$	Threshold voltage		150	1,15	V
r_F	Forward slope resistance		150	0,685	mohm
SWITCHING					
t_{rr}	Reverse recovery time	IF= 350A	150	4	µs
Q_{rr}	Reverse recovery charge	di/dt= 80 A/µs		260	µC
I_{rr}	Peak reverse recovery current	VR= 100V		140	A
s	Softness (s-factor), min			0,4	
V_{FR}	Peak forward recovery	di/dt = 400 A/µs	150	20	V
MOUNTING					
$R_{th(j-h)}$	Thermal impedance, DC	Junction to heatsink, double side cooled		52,0	°C/kW
$R_{th(c-h)}$	Thermal impedance	Case to heatsink, double side cooled		10,0	°C/kW
T_j	Operating junction temperature			-30 / 150	°C
F	Mounting force			8.4 / 9.4	kN
	Mass			280	g

ORDERING INFORMATION : ARF912 S 26

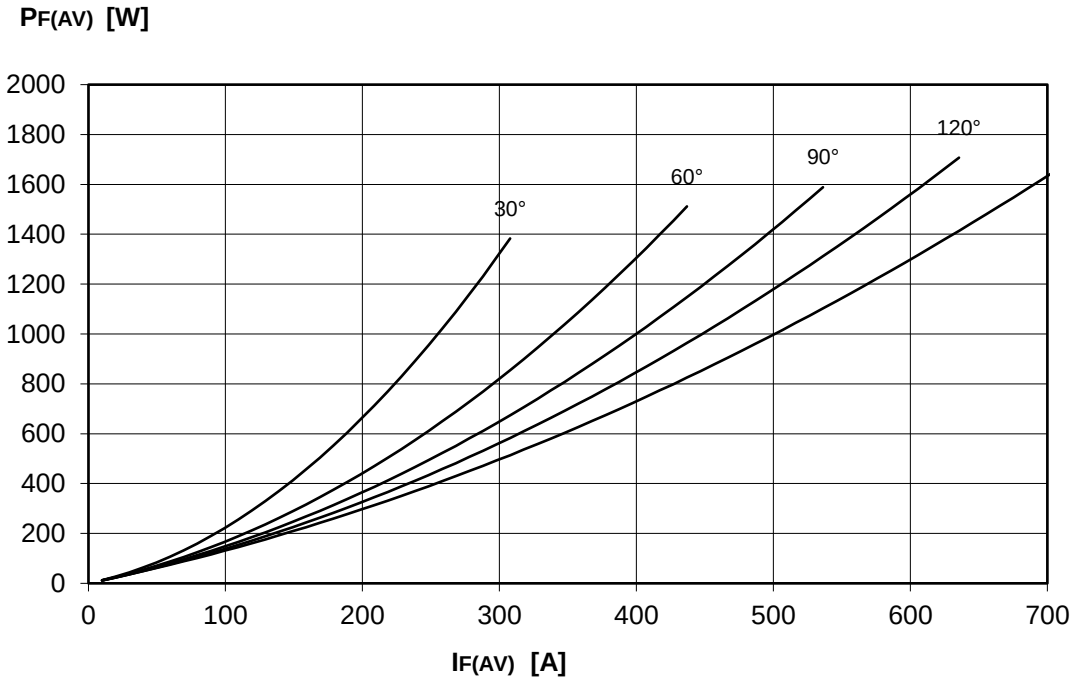
standard specification — VRRM/100

DISSIPATION CHARACTERISTICS

SQUARE WAVE (50Hz)



SINE WAVE (50Hz)



ARF912 FAST RECOVERY DIODE

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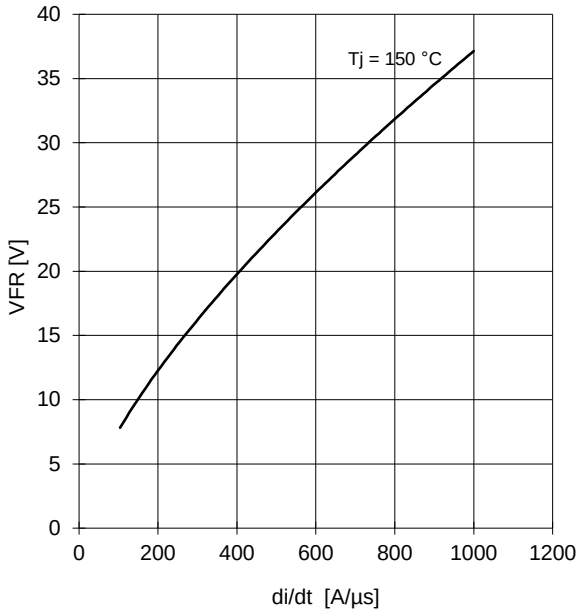
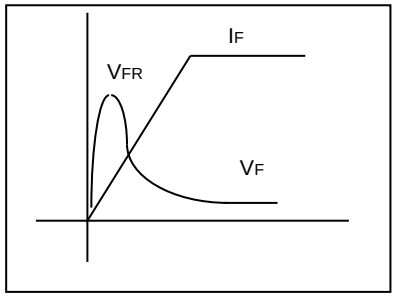
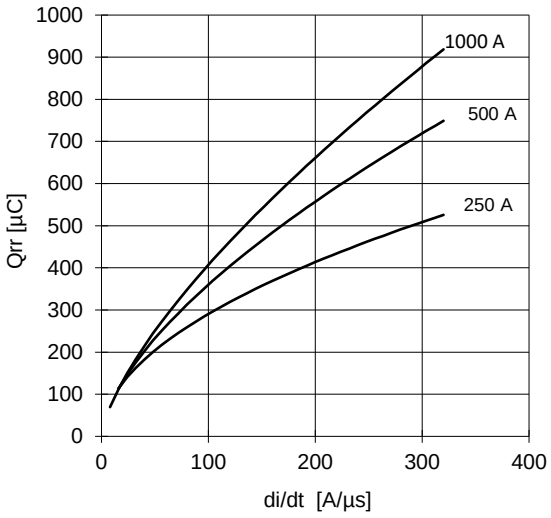
FORWARD RECOVERY VOLTAGE

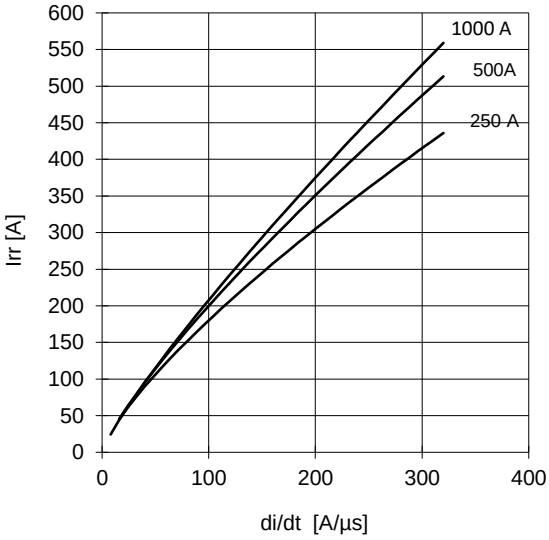




REVERSE RECOVERY CHARGE
Tj = 150 °C



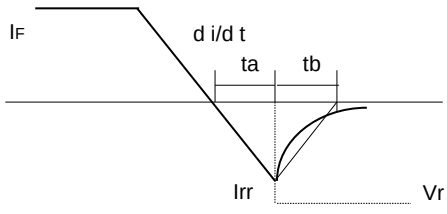
REVERSE RECOVERY CURRENT
Tj = 150 °C



ta = Irr / (di/dt) tb = trr - ta

Softness (s factor) s = tb / ta

Energy dissipation during recovery Er = Vr ·(Qrr - Irr ·ta / 2)

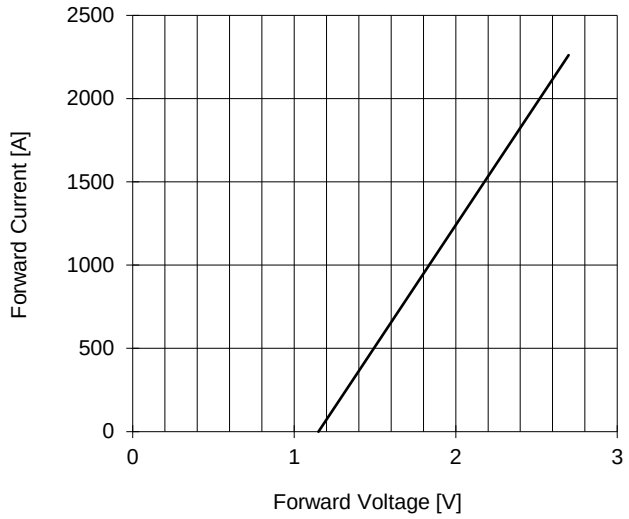


ARF912 FAST RECOVERY DIODE

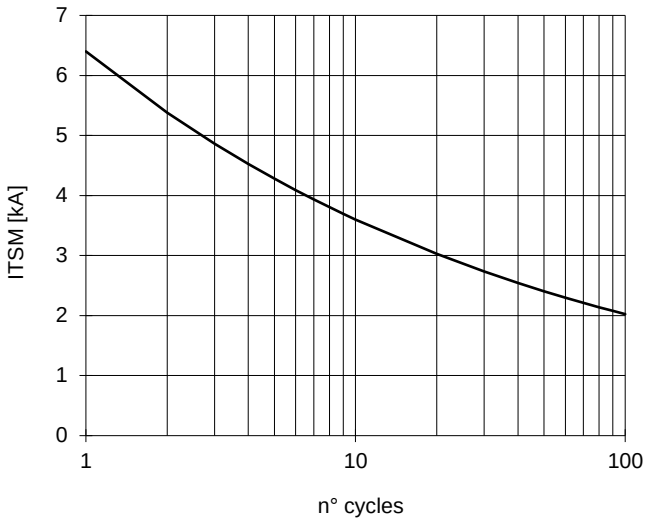
POSEICO POWER ELECTRONICS

FINAL SPECIFICATION June 17 - Issue: 5

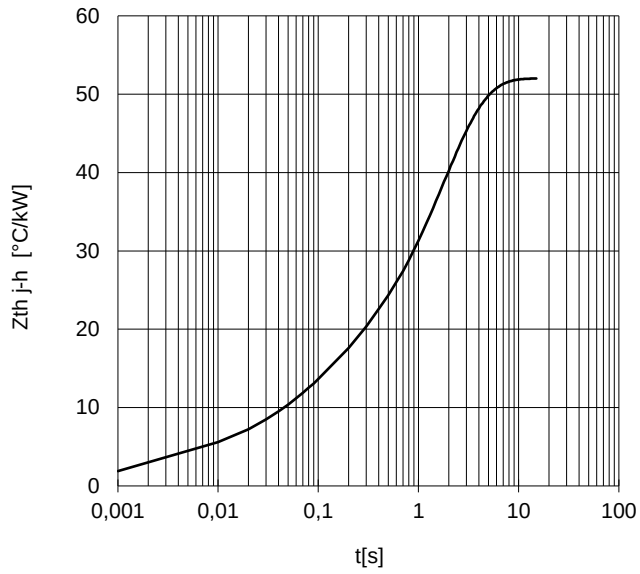
FORWARD CHARACTERISTIC
Tj = 150 °C

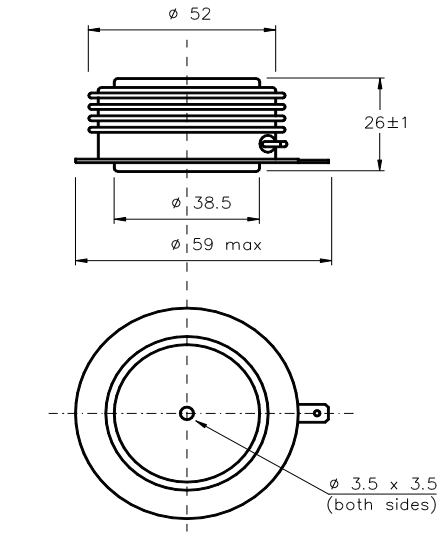


SURGE CHARACTERISTIC
Tj = 150 °C



TRANSIENT THERMAL IMPEDANCE
DOUBLE SIDE COOLED





Dimensions in mm

All the characteristics given in this data sheet are guaranteed only with uniform clamping force, cleaned and lubricated heatsink, surfaces with flatness < .03 mm and roughness < 2 µm.
In the interest of product improvement POSEICO SpA reserves the right to change any data given in this data sheet at any time without previous notice.
If not stated otherwise the maximum value of ratings (simbols over shaded background) and characteristics is reported.

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